## Si nanoparticles: New photonic and electronic material





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## NanoSi Let there be Light

#### Nature

news feature

### Let there be light

A silicon laser would revolutionize telecommunications electronics and computing. Squeezing light out of silicon is no easy task, but Philip Ball discovers that researchers are becoming more optimistic about its light-emitting abilities.

Tantalizingly, at the Materials Research Society meeting in Boston last December, Nayfeh reported optical gain and stimulated emission from his blue-light-emitting nanocrystals. Others in the field are now waiting for Nayfeh to publish quantitative data so that they can assess these claims.

#### Dot comms

Using a network of silicon wires is not the only way to make the element glow. The same helpful quantum effects operate if the porous silicon is divided into nanometresized particles known as nanocrystals or 'quantum dots'. Last year, Munir Nayfeh of the University of Illinois at Urbana-Champaign and his colleagues used ultrasound to shatter porous silicon into nanocrystals. The smallest of these particles (about 1 nanometre across) emit blue light<sup>5</sup>.



## From bulk to nanoparticles

#### What makes silicon Glow?

#### I) Bulk Silicon (Emission lifetime ~ ms) Dull

- Difficult to conserve momentum in transition across bandgap. (Indirect gap)
- Momentum can come from coupling to crystalline phonons. (2<sup>nd</sup> order process)

#### II) Si Nanostructure > 3nm (Enhanced lifetime ~ us) Fluorescent

- *Quantum confinement* with bulk-like emission
- Momentum can come from coupling to crystalline
   phonons
- Additional momentum can come from boundary scattering of electrons (dk dx larger than 1).

#### III) Si nanoparticle (1-3nm) (Enhanced lifetime ~ ns) Glow

 Trapping of excitons onto atomic intrinsic sites (Siexample) where the conservation of momentum i lifted. (direct gap?)

#### Combination of mechanisms

- Space confinement
- Molecular confinement Self-trapped
- Other?









## Process and purification

#### Electrochemical etch of bulk wafers

1-10 ohm-cm p-type <100> Si Current concentrates at meniscus (~30mA/cm2) Particles dispersed in a solvent via sonication

Particles produced are H-passivated.

**Particles purified** by size via gel permeation chromatography; Fractions exhibit different luminescence spectra



#### Electrochemical Process Makes Ultrasmall Si Nanoparticles

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MRS

Researchers at the University of Ilinois—Urbana-Champaign have developed a process for converting bulk silicon into ultrasmall, nano-sized particles. As reported in the April 3 issue of *Applied Physics Letters*, the nanoparticles—which are about 1 nm in diameter and contain wafer is then removed from the etchant and immersed briefly in an ultrasound bath." The main contents of the etchant bath are hydrogen fluoride (HF) and hydrogen peroxide ( $H_2O_2$ ).

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Under the ultrasound treatment, the fragile nanostructure network crumbles into individual particles of different size groups, Nayfeh said. The slightly larger, heavier particles precipitate out, while the

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Z. Yamani, H. Thompson, L. AbuHassan, and M. H. Nayfeh , Appl. Phys. Lett. 70, 3404-3406 (1997)

## Sweet spots in Si cluster size



A family of magic sizes of hydrogenated Si nanoparticles No magic sizes > 20 atoms for nonhydrogenated clusters



#### A family of silicon nanoparticles

A new method for creating Once dry, the aggregates are silicon (Si) nanoparticles has encapsulated with an acrylic been developed by researchers polymer. The researchers find that the aggregates produced at the University of Illinois at Urbana-Champaign. in this way exhibit laser Munir Nayfeh and his oscillation under cw excitation colleagues describe the new by a mercury lamp. Intense, directed Gaussian beams, with electrochemical etching band narrowing and speckle process in two recent papers in Applied Physics Letters patterns can be seen, say the [(7 Jan 2002), 80 (1), 121researchers. "At 6 µm in 123; (4 February 2002), 80 diameter, these clusters of (5), 841-843). Performing particles are one of the











G. Belomoin, J. Therrien, A. Smith, S. Rao, S. Chaieb, M. H. Nayfeh, Appl. Phys. Lett. 80, 841 (2002)

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Z. Yamani, S. Ashhab, A. Nayfeh and M. H. Nayfeh, J. Appl. Phys. 83, 3929-3931 (1998)

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## Silicon Nanoparticle prototype

(Quantum Monte Carlo simulation)

I. Ideal bulk-like configuration (Band gap of 3.6-3.7 eV)

- Filled fullerene configuration
- •Tetrahedral Si core (5 atoms)
- •24 hydrogen passivated cage
- Known position of Si and H
- Highly rinckled (puckerred ball) (pentagons and hexagons)
- 1 Td atom and 28 atom fullerene cage



29 Silicon (<mark>yellow</mark>) 24 Hydrogen (white)



L. Mitas, J. Therrien, R. Twesten, G. Belomoin, and M. H. Nayfeh, appl. Phys. Lett. 78, 1918 (2001)

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## Wide bandgap mateial:

Reconstitution into films and solids

The particles are harvested in a solution. Particles may then be processed into a certain assay using:

Spray
Spray
Set
Electrochemical deposition

### Produces wide bandgap solids











(from Acetone)

# From bulk band structure to molecular bands (Excited states of Si29)

## Molecular-like excited state bands --- Richard Martin

Excitation spectra (absorption x emission)



Time dependent LDH theory



S. Rao, J. Sutin, R. Clegg, E. Gratton, M. Nayfeh, S. Habbal, A. Tsolakidis, R. Martin, Phys. Rev. B (2004)

#### **Bulk absorption**



## Single-Electron Transistors and Memory Cells

A single-electron transis-tor (SET) is a three-terminal device, with gate, source, and drain.

#### Memory Nano- cells



*Electronic applications* (e.g., low-power electronics, nonvolatile floating gate memory): Unlike traditional transistors, silicon nanoparticles can capture/emit a single electron with an energy spacing on the order of 1 electron volt, enabling the manufacture of devices with single-electron operation at room temperature with significantly lower power requirements.





## Nano memory on a super chip

Metal-oxide-silicon (MOS)

**Capacitor memory** 

Contain uniform 1 nm silicon nanoparticles







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Black(1), Red(2), Blue(3), Orange(5), Turq(8), Purple(10)

